High Voltage Transistors NPN Silicon

COLLECTOR 3 BASE 1 EMITTER

MAXIMUM RATINGS

| Rating | Symbol | MPSA42 | MPSA43 | Unit |
|---|-----------------------------------|-------------|--------|----------------|
| Collector-Emitter Voltage | VCEO | 300 | 200 | Vdc |
| Collector-Base Voltage | Vсво | 300 | 200 | Vdc |
| Emitter-Base Voltage | VEBO | 6.0 | 6.0 | Vdc |
| Collector Current — Continuous | IC | 500 | | mAdc |
| Total Device Dissipation @ T _A = 25°C Derate above 25°C | PD | 625 5.0 | | mW mW/°C |
| Total Device Dissipation @ T _C = 25°C Derate above 25°C | PD | 1.5 12 | | Watts mW/°C |
| Operating and Storage Junction Temperature Range | T _J , T _{stg} | -55 to +150 | | °C |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---|-----------------|------|-------|
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 200 | °C/mW |
| Thermal Resistance, Junction to Case | $R_{\theta JC}$ | 83.3 | °C/mW |

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | | Symbol | Min | Max | Unit |
|--|------------------|----------------------|-------------|------------|------|
| OFF CHARACTERISTICS | | | | | |
| Collector-Emitter Breakdown Voltage ⁽¹⁾ (IC = 1.0 mAdc, IB = 0) | MPSA42 MPSA43 | V(BR)CEO | 300 200 | | Vdc |
| Collector-Base Breakdown Voltage (I _C = 100 μAdc, I _E = 0) | MPSA42 MPSA43 | V _{(BR)CBO} | 300 200 | _ _ | Vdc |
| Emitter-Base Breakdown Voltage ($I_E = 100 \mu Adc$, $I_C = 0$) | | V(BR)EBO | 6.0 | _ | Vdc |
| Collector Cutoff Current (V _{CB} = 200 Vdc, I _E = 0) (V _{CB} = 160 Vdc, I _E = 0) | MPSA42 MPSA43 | I _{CBO} | _ _ _ | 0.1 0.1 | μAdc |
| Emitter Cutoff Current $(V_{EB} = 6.0 \text{ Vdc}, I_{C} = 0)$ $(V_{EB} = 4.0 \text{ Vdc}, I_{C} = 0)$ | MPSA42 MPSA43 | I _{EBO} | _ _ | 0.1 0.1 | μAdc |

^{1.} Pulse Test: Pulse Width \leq 300 $\mu\text{s},$ Duty Cycle \leq 2.0%.

Preferred devices are Motorola recommended choices for future use and best overall value.

MPSA42* MPSA43

*Motorola Preferred Device





MPSA42 MPSA43

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted) (Continued)

| Characteristic | | Symbol | Min | Max | Unit |
|--|------------------|----------------------|----------------|-------------|------|
| ON CHARACTERISTICS(1) | | • | | • | |
| DC Current Gain (I _C = 1.0 mAdc, V_{CE} = 10 Vdc) (I _C = 10 mAdc, V_{CE} = 10 Vdc) (I _C = 30 mAdc, V_{CE} = 10 Vdc) | | hFE | 25 40 40 | _ _ _ | _ |
| Collector-Emitter Saturation Voltage (I _C = 20 mAdc, I _B = 2.0 mAdc) | MPSA42 MPSA43 | V _{CE(sat)} | _ _ | 0.5 0.4 | Vdc |
| Base–Emitter Saturation Voltage (I _C = 20 mAdc, I _B = 2.0 mAdc) | | V _{BE(sat)} | _ | 0.9 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | | | | • | |
| Current-Gain — Bandwidth Product (I _C = 10 mAdc, V _{CE} = 20 Vdc, f = 100 MHz) | | fΤ | 50 | _ | MHz |
| Collector–Base Capacitance (V _{CB} = 20 Vdc, I _E = 0, f = 1.0 MHz) | MPSA42 MPSA43 | C _{cb} | _ _ | 3.0 4.0 | pF |

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

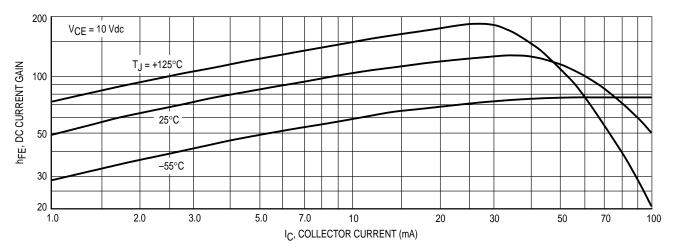


Figure 1. DC Current Gain

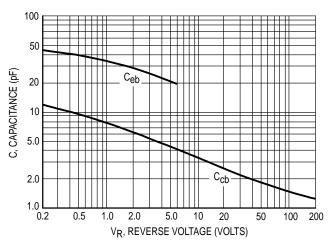


Figure 2. Capacitances

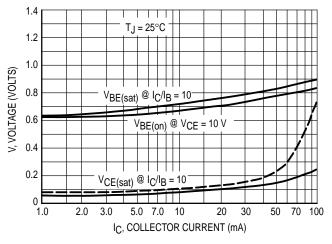


Figure 4. "On" Voltages

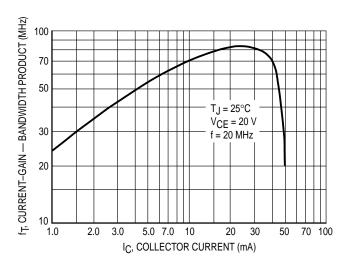


Figure 3. Current-Gain — Bandwidth Product

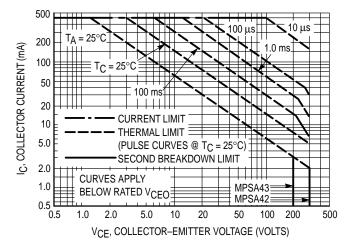
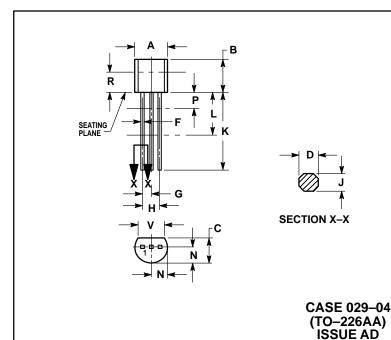


Figure 5. Maximum Forward Bias Safe Operating Area

PACKAGE DIMENSIONS



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: INCH.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN P AND L. DIMENSION F APPLIES BETWEEN F AIND L.
 DIMENSION D AND J APPLY BETWEEN L AND K
 MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

| | INCHES | | MILLIN | IETERS |
|-----|--------|-------|--------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.175 | 0.205 | 4.45 | 5.20 |
| В | 0.170 | 0.210 | 4.32 | 5.33 |
| С | 0.125 | 0.165 | 3.18 | 4.19 |
| D | 0.016 | 0.022 | 0.41 | 0.55 |
| F | 0.016 | 0.019 | 0.41 | 0.48 |
| G | 0.045 | 0.055 | 1.15 | 1.39 |
| Н | 0.095 | 0.105 | 2.42 | 2.66 |
| J | 0.015 | 0.020 | 0.39 | 0.50 |
| K | 0.500 | | 12.70 | |
| L | 0.250 | | 6.35 | |
| N | 0.080 | 0.105 | 2.04 | 2.66 |
| Р | | 0.100 | | 2.54 |
| R | 0.115 | | 2.93 | |
| ٧ | 0.135 | | 3.43 | |

STYLE 1: PIN 1. EMITTER BASE

3. COLLECTOR

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